



INTEGRATED TECHNICAL EDUCATION CLUSTER  
AT ALAMEERIA

**J-601-1448**

**Electronic Principles**

Lecture #9

Tuned Amplifiers

**Instructor:**

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# Agenda

- Class C vs. Tuned Amplifier
- Basic Operation
- Tuned Operation
- Sharpness of Resonance
- Clamper Bias

# CLASS C VS. TUNED AMPLIFIER



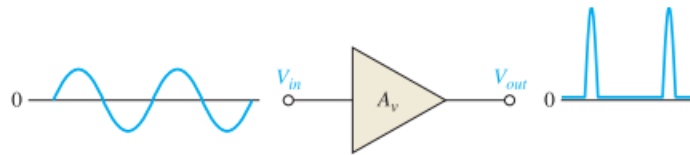
# Introduction

- Class C amplifiers are biased so that conduction occurs for much less than  $180^\circ$ .
- Class C amplifiers are more efficient than either class A or push-pull class B and class AB, which means that more output power can be obtained from class C operation.
- The output amplitude is a nonlinear function of the input, so class C amplifiers are not used for linear amplification.
- They are generally used in radio frequency (RF) applications, including circuits, such as
  - oscillators, that have a constant output amplitude
  - modulators, where a high-frequency signal is controlled by a low-frequency signal.
- Therefore, Class C amplifiers are also called Tuned Amplifiers.
- An amplifier which amplifies a specific frequency ( or a narrow band of frequencies) is called a *tuned voltage amplifier*.
- It has two purposes:
  - Selection of a desired radio frequency signal.
  - Amplification of the selected signal to a suitable voltage level.

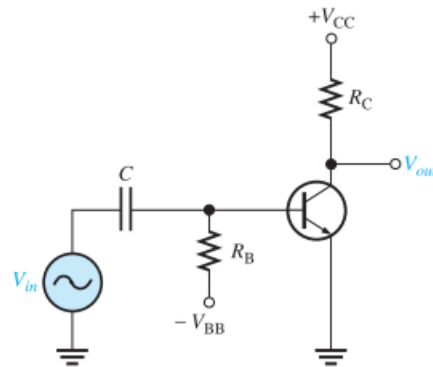
# BASIC OPERATION



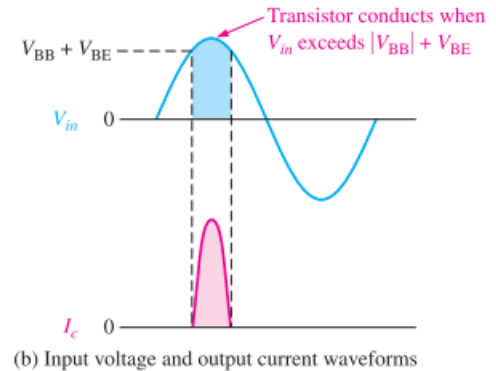
# Class C operation



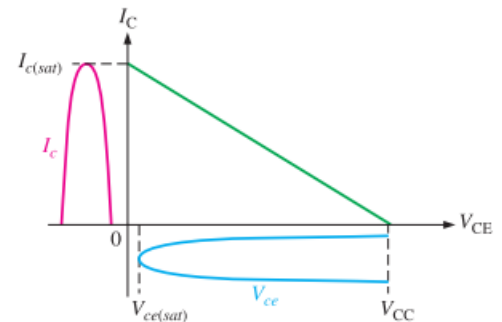
- It is biased below cutoff with the negative  $V_{BB}$  supply.
- A class C amplifier is normally operated with a resonant circuit load, so the resistive load is used only for the purpose of illustrating the concept.



(a) Basic class C amplifier circuit

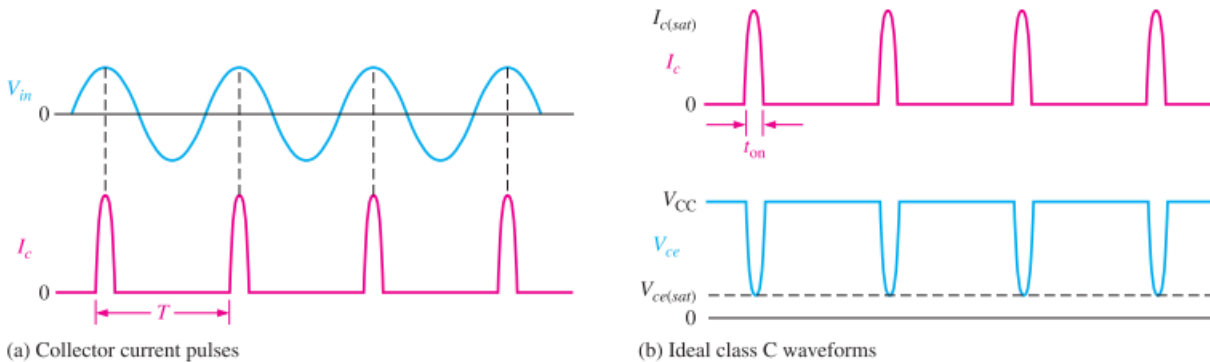


(b) Input voltage and output current waveforms



(c) Load line operation

# Power Dissipation



- The power dissipation of the transistor in a class C amplifier is low because it is on for only a small percentage of the input cycle.
- To avoid complex mathematics, we will assume ideal pulse approximations.
- Using this simplification, if the output swings over the entire load, the maximum current amplitude is  $I_c(sat)$  and the minimum voltage amplitude is  $V_{ce}(sat)$  during the time the transistor is on.
- The power dissipation during the on time is  $P_{D(on)} = I_c(sat)V_{ce}(sat)$
- The transistor is on for a short time,  $t_{on}$ , and off for the rest of the input cycle.
- The power dissipation averaged over the entire cycle is

$$P_{D(avg)} = \left(\frac{t_{on}}{T}\right)P_{D(on)} = \left(\frac{t_{on}}{T}\right)I_c(sat)V_{ce}(sat)$$

Check EXAMPLE 7–7!

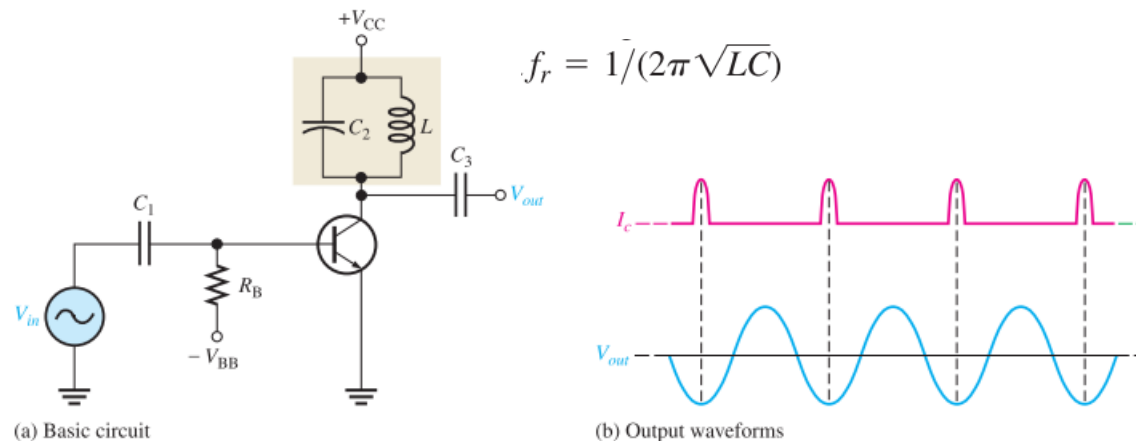
# TUNED OPERATION





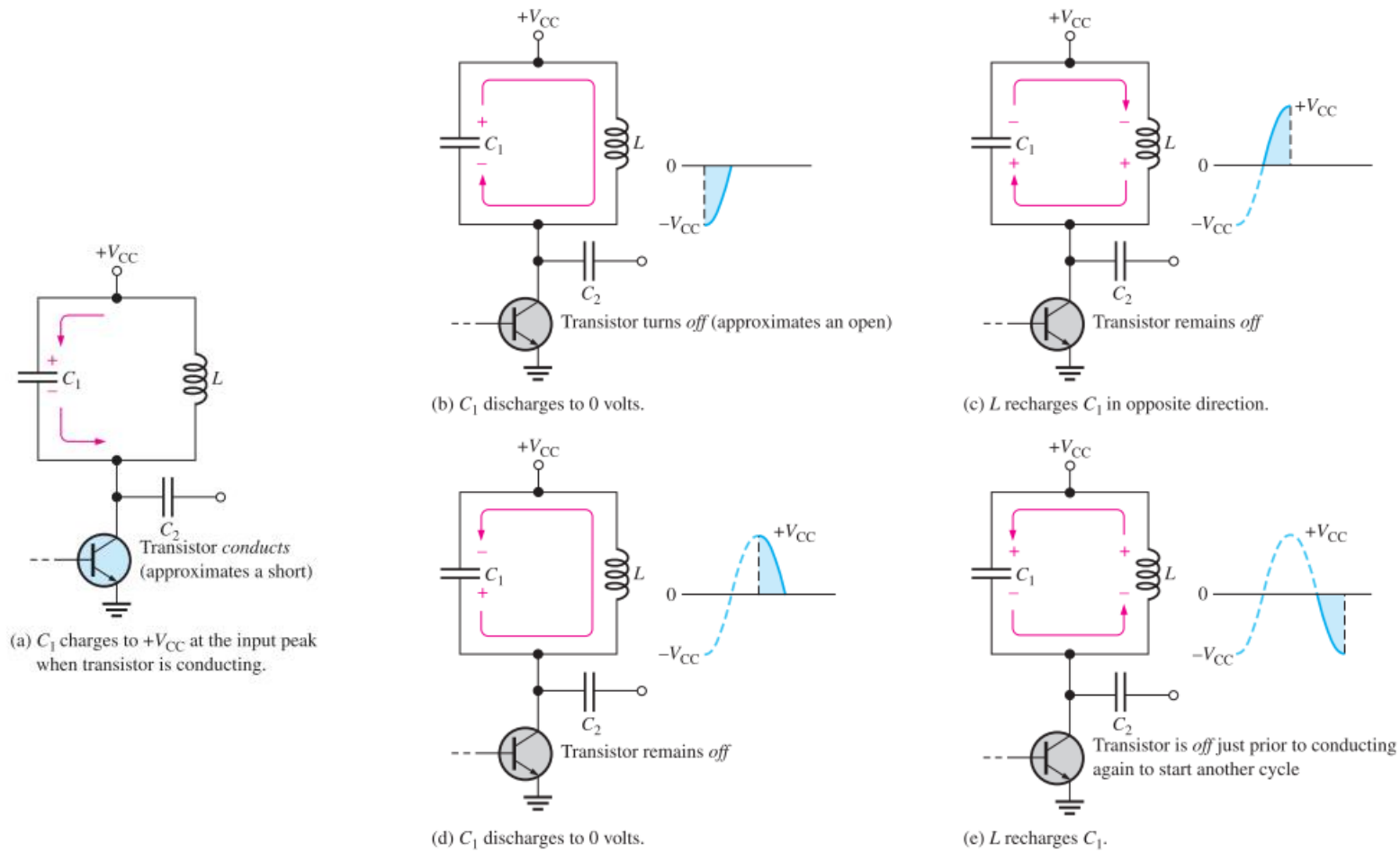
# Usage of Parallel Resonance Circuit

- Because the collector voltage (output) is not a replica of the input, the resistively loaded class C amplifier alone is of no value in linear applications.
- It is therefore necessary to use a class C amplifier with a parallel resonant circuit (tank).
- The short pulse of collector current on each cycle of the input initiates and sustains the oscillation of the tank circuit so that an output sinusoidal voltage is produced.
- The tank circuit has high impedance only near the resonant frequency, so the gain is large only at this frequency.



▲ FIGURE 7-24  
Tuned class C amplifier.

# Resonant Circuit Action



▲ FIGURE 7-25

Resonant circuit action.

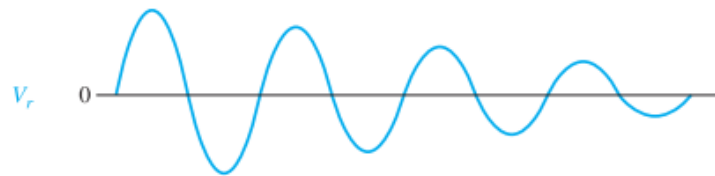
# SHARPNESS OF RESONANCE



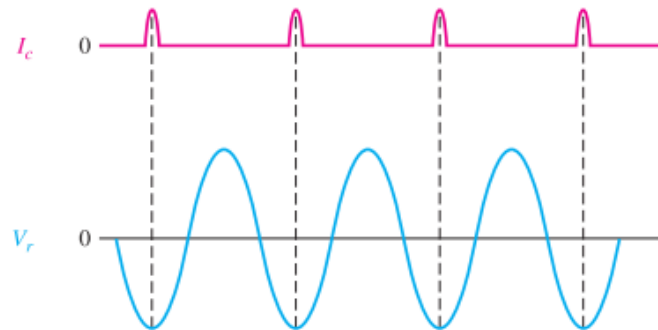
# Resonant Circuit Action..

► FIGURE 7-26

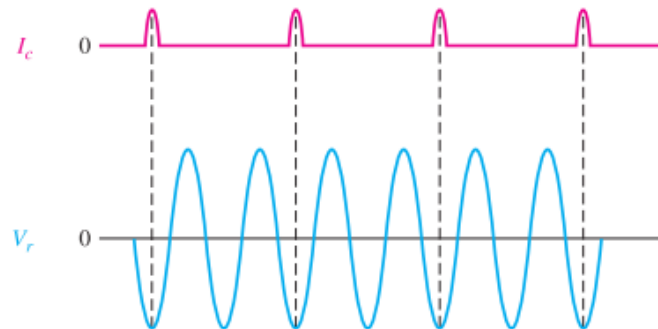
Tank circuit oscillations.  $V_r$  is the voltage across the tank circuit.



(a) An oscillation will gradually die out (decay) due to energy loss. The rate of decay depends on the efficiency of the tank circuit.



(b) Oscillation at the fundamental frequency can be sustained by short pulses of collector current.



(c) Oscillation at the second harmonic frequency

frequency multiplier (x2) →

# Resonance Curve Sharpness

- The resonance curve is required to be as sharp as possible in order to provide a high selectivity.
- A sharp resonance curve means that the impedance falls off rapidly as the frequency is varied above and below the resonant frequency.

$$\text{Sharpness of resonance} = \frac{\text{Bandwidth}}{\text{Resonant frequency}} = \frac{BW}{f_o} = \frac{f_2 - f_1}{f_o} = \frac{1}{Q_o}$$

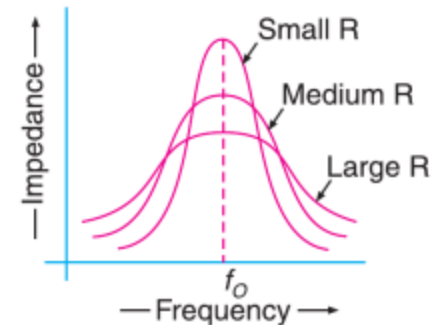
$$\text{the } Q\text{-factor; } Q_o = \frac{X_L}{R} = \frac{\omega_o \cdot L}{R} = \frac{2\pi f_o \cdot L}{R}$$

$L$  = Value of circuit inductance, and

$R$  = Value of circuit resistance or coil resistance.

$$BW = \frac{f_o}{Q_o}$$

$$f_o = BW \times Q_o$$



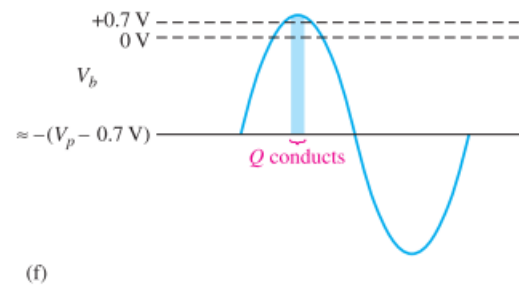
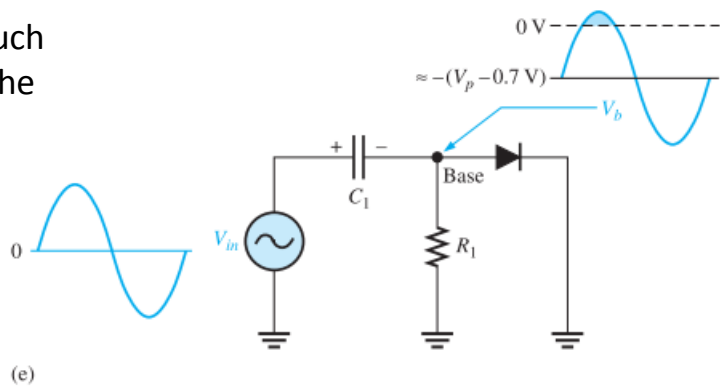
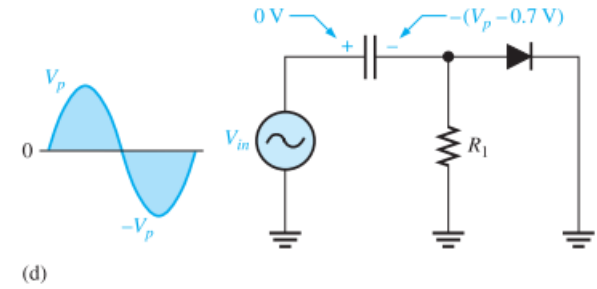
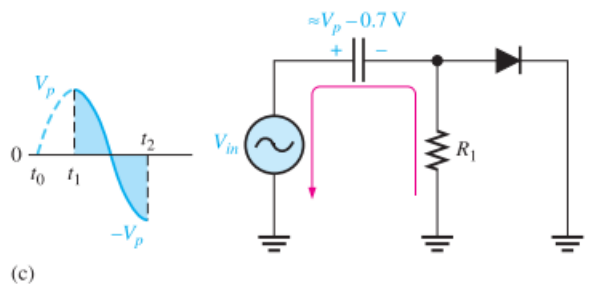
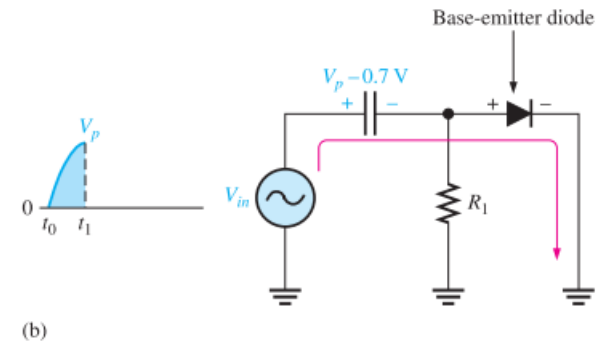
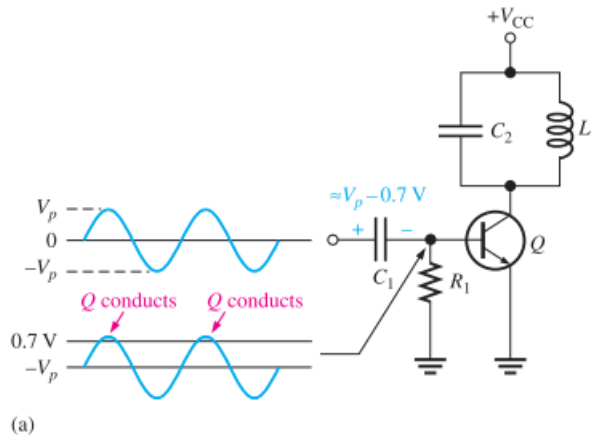
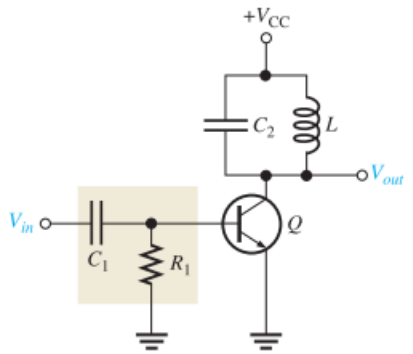
**Fig. 28.5.** Effect of coil resistance ( $R$ ) on the sharpness of resonance curves.

- A higher value of quality factor ( $Q_o$ ) provides a higher selectivity but a smaller bandwidth and vice versa.

# CLAMPER BIAS



# Clamper Bias



For good clamping action, the  $R_1C_1$  time constant of the clamping circuit must be much greater than the period of the input signal.

▲ FIGURE 7-28  
Clamper bias action.



- For more details, refer to:
  - Chapter 7, section 7-3, T. Floyd, **Electronic Devices**, 9<sup>th</sup> edition.
  - Chapter 28, section 28.5, Sedha, **Text Book of Applied Electronics**, 2003.
- The lecture is available online at:
  - [https://speakerdeck.com/ahmad\\_elbanna](https://speakerdeck.com/ahmad_elbanna)
- For inquiries, send to:
  - [ahmad.elbanna@feng.bu.edu.eg](mailto:ahmad.elbanna@feng.bu.edu.eg)